

# FBR1000 - FBR1010

**PRV : 50 - 1000 Volts**  
**Io : 10 Amperes**

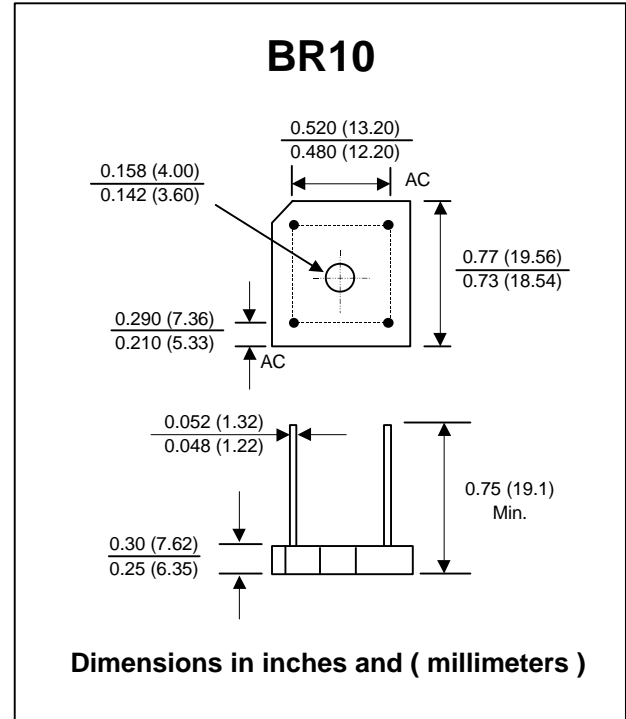
## FEATURES :

- \* High case dielectric strength
- \* High surge current capability
- \* High reliability
- \* Low reverse current
- \* Low forward voltage drop
- \* Fast switching for high efficiency
- \* Ideal for printed circuit board
- \* **Pb / RoHS Free**

## MECHANICAL DATA :

- \* Case : Reliable low cost construction utilizing molded plastic technique
- \* Epoxy : UL94V-O rate flame retardant
- \* Lead : Axial lead solderable per MIL - STD 202 , Method 208 guaranteed
- \* Polarity : Polarity symbols marked on case
- \* Mounting position : Any
- \* Weight : 6.1 grams

## FAST RECOVERY BRIDGE RECTIFIERS



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

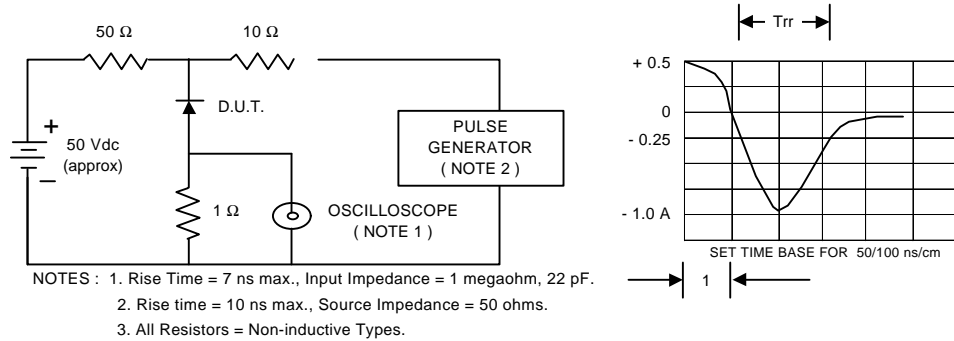
RATING	SYMBOL	FBR 1000	FBR 1001	FBR 1002	FBR 1004	FBR 1006	FBR 1008	FBR 1010	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Current Tc = 55 °C	I <sub>F(AV)</sub>	10							A
Peak Forward Surge Current Single half sine wave Superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	250							A
Current Squared Time at t < 8.3 ms.	I <sup>2</sup> t	160							A <sup>2</sup> S
Maximum Forward Voltage drop per Diode at I <sub>F</sub> = 5.0 A	V <sub>F</sub>	1.3							V
Maximum DC Reverse Current Ta = 25 °C at Rated DC Blocking Voltage Ta = 100 °C	I <sub>R</sub>	10							μA
	I <sub>R(H)</sub>	200							μA
Maximum Reverse Recovery Time (Note 1)	T <sub>rr</sub>	150			250		500		ns
Typical Thermal Resistance per diode (Note 2)	R <sub>θJC</sub>	2.5							°C/W
Operating Junction Temperature Range	T <sub>J</sub>	- 50 to + 150							°C
Storage Temperature Range	T <sub>STG</sub>	- 50 to + 150							°C

### Notes :

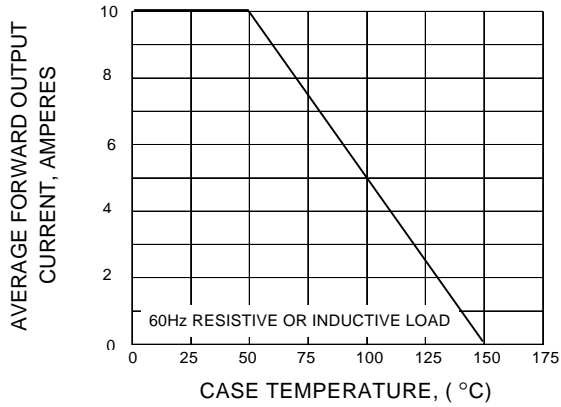
- 1) Measured with I<sub>F</sub> = 0.5 Amp., I<sub>R</sub> = 1 Amp., I<sub>rr</sub> = 0.25 Amp.
- 2) Thermal Resistance from junction to case with units mounted on a 3.2" x 3.2" x 0.12" THK (8.2cm.x 8.2cm.x 0.3cm.) Al. Plate. heatsink.

## RATING AND CHARACTERISTIC CURVES ( FBR1000 - FBR1010 )

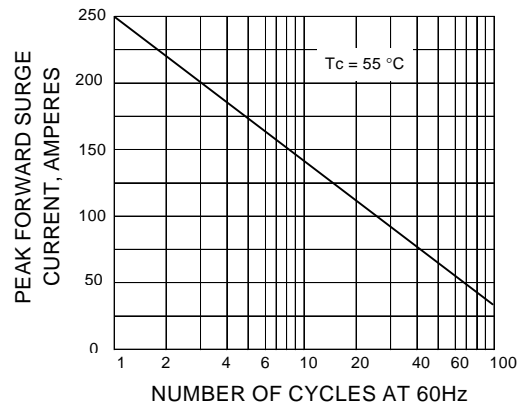
**FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**



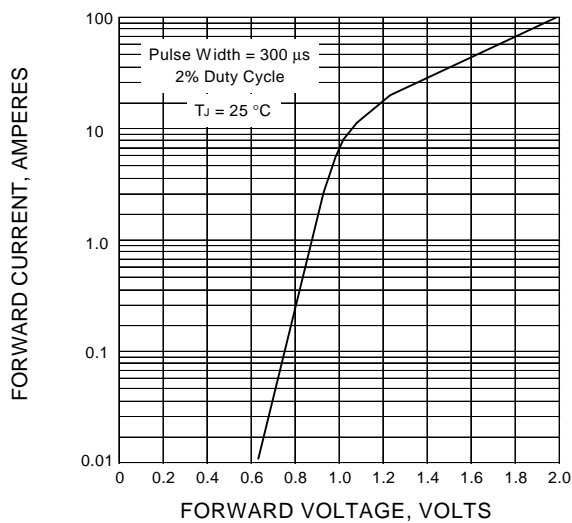
**FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT**



**FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG.4 - TYPICAL FORWARD CHARACTERISTICS PER DIODE**



**FIG.5 - TYPICAL REVERSE CHARACTERISTICS PER DIODE**

